

# MMBFU310LT1G

## JFET Transistor

### N-Channel

#### Features

- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	25	Vdc
Gate-Source Voltage	$V_{GS}$	25	Vdc
Gate Current	$I_G$	10	mAdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

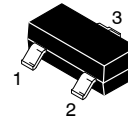
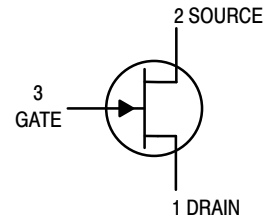
Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	225	mW
		1.8	mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.



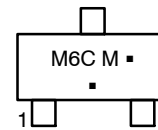
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SOT-23 (TO-236AB)  
CASE 318-08  
STYLE 10

#### MARKING DIAGRAM



M6C = Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### ORDERING INFORMATION

Device	Package	Shipping†
MMBFU310LT1G	SOT-23 (Pb-Free)	3000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MMBFU310LT1G

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Gate-Source Breakdown Voltage - ( $I_G = -1.0 \mu\text{A}$ , $V_{DS} = 0$ )	$V_{(BR)GSS}$	-25	-	Vdc
Gate 1 Leakage Current - ( $V_{GS} = -15 \text{ Vdc}$ , $V_{DS} = 0$ )	$I_{G1SS}$	-	-150	pA
Gate 2 Leakage Current - ( $V_{GS} = -15 \text{ Vdc}$ , $V_{DS} = 0$ , $T_A = 125^\circ\text{C}$ )	$I_{G2SS}$	-	-150	nA
Gate Source Cutoff Voltage - ( $V_{DS} = 10 \text{ Vdc}$ , $I_D = 1.0 \text{ nA}$ )	$V_{GS(off)}$	-2.5	-6.0	Vdc

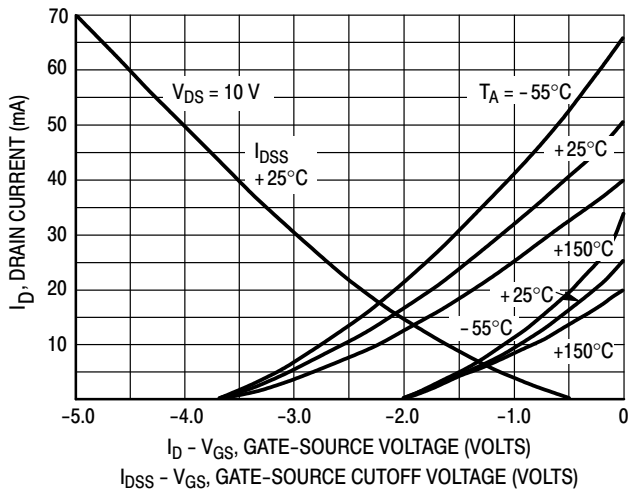
## ON CHARACTERISTICS

Zero-Gate-Voltage Drain Current - ( $V_{DS} = 10 \text{ Vdc}$ , $V_{GS} = 0$ )	$I_{DSS}$	24	60	mA
Gate-Source Forward Voltage - ( $I_G = 10 \text{ mA}$ , $V_{DS} = 0$ )	$V_{GS(f)}$	-	1.0	Vdc

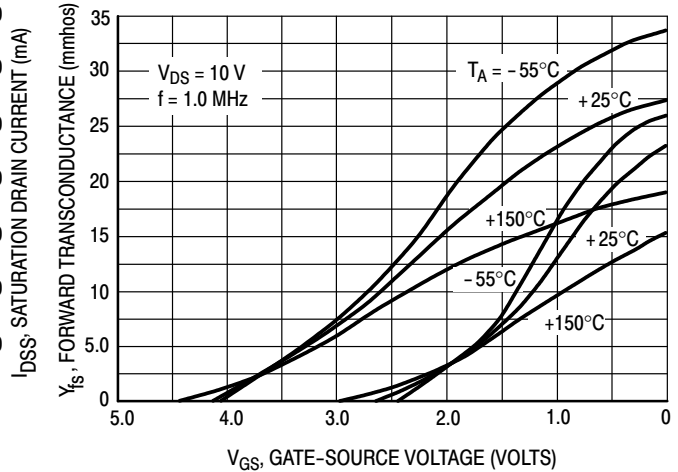
## SMALL-SIGNAL CHARACTERISTICS

Forward Transfer Admittance - ( $V_{DS} = 10 \text{ Vdc}$ , $I_D = 10 \text{ mA}$ , $f = 1.0 \text{ kHz}$ )	$ Y_{fs} $	10	18	mmhos
Output Admittance - ( $V_{DS} = 10 \text{ Vdc}$ , $I_D = 10 \text{ mA}$ , $f = 1.0 \text{ kHz}$ )	$ y_{os} $	-	250	$\mu\text{mhos}$
Input Capacitance - ( $V_{GS} = -10 \text{ Vdc}$ , $V_{DS} = 0 \text{ Vdc}$ , $f = 1.0 \text{ MHz}$ )	$C_{iss}$	-	5.0	pF
Reverse Transfer Capacitance - ( $V_{GS} = -10 \text{ Vdc}$ , $V_{DS} = 0 \text{ Vdc}$ , $f = 1.0 \text{ MHz}$ )	$C_{rss}$	-	2.5	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

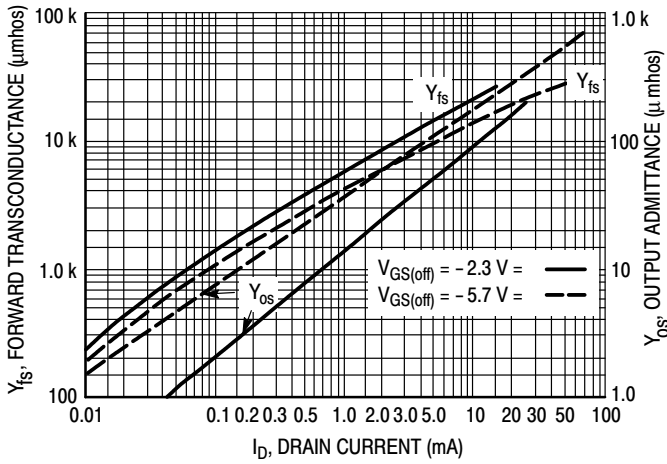


**Figure 1. Drain Current and Transfer Characteristics vs Gate-Source Voltage**

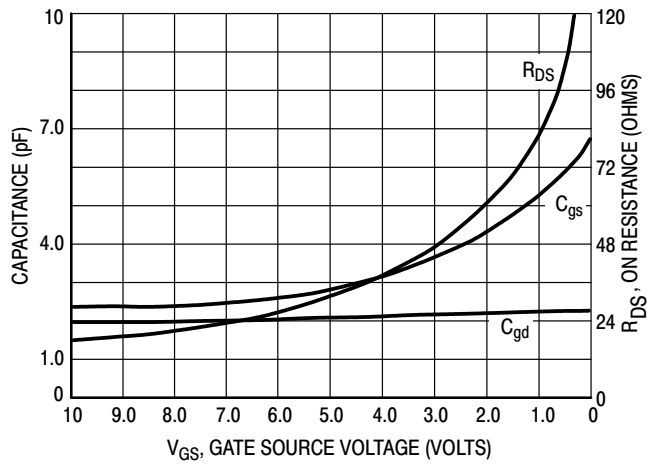


**Figure 2. Forward Transconductance vs Gate-Source Voltage**

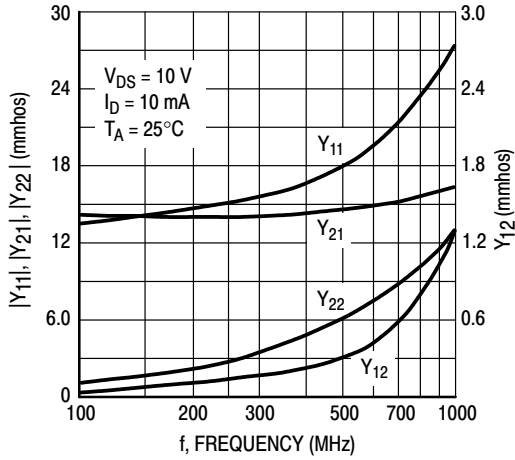
# MMBFU310LT1G



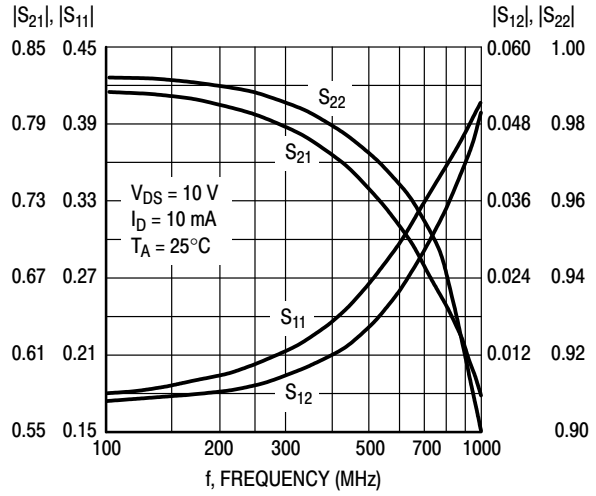
**Figure 3. Common-Source Output Admittance and Forward Transconductance vs Drain Current**



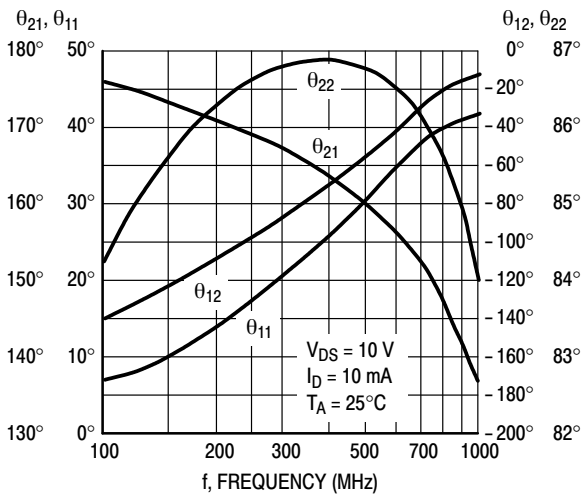
**Figure 4. On Resistance and Junction Capacitance vs Gate-Source Voltage**



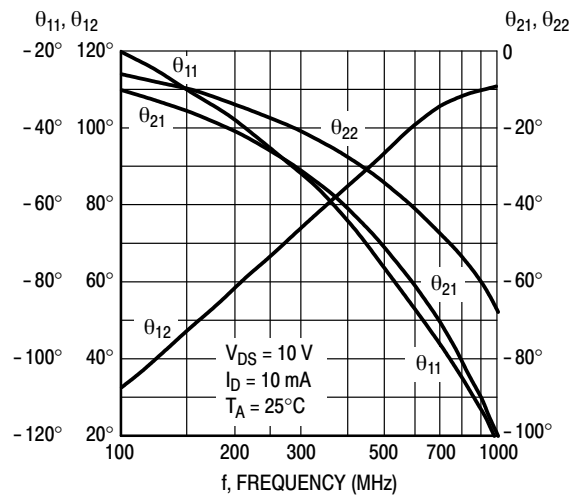
**Figure 5. Common-Gate Y Parameter Magnitude vs Frequency**



**Figure 6. Common-Gate S Parameter Magnitude vs Frequency**



**Figure 7. Common-Gate Y Parameter Phase-Angle vs Frequency**



**Figure 8. S Parameter Phase-Angle vs Frequency**

# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



**SOT-23 (TO-236)**  
CASE 318  
ISSUE AT

DATE 01 MAR 2023

SCALE 4:1



**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

DIM	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
c	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
H <sub>E</sub>	2.10	2.40	2.64	0.083	0.094	0.104
T	0°	---	10°	0°	---	10°

**GENERIC MARKING DIAGRAM\***



- XXX = Specific Device Code
- M = Date Code
- = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.



**RECOMMENDED MOUNTING FOOTPRINT**

\* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**STYLES ON PAGE 2**

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**MECHANICAL CASE OUTLINE  
PACKAGE DIMENSIONS**



**SOT-23 (TO-236)  
CASE 318  
ISSUE AT**

DATE 01 MAR 2023

- STYLE 1 THRU 5:  
CANCELLED
- STYLE 6:  
PIN 1. BASE  
2. EMITTER  
3. COLLECTOR
- STYLE 7:  
PIN 1. EMITTER  
2. BASE  
3. COLLECTOR
- STYLE 8:  
PIN 1. ANODE  
2. NO CONNECTION  
3. CATHODE
- STYLE 9:  
PIN 1. ANODE  
2. ANODE  
3. CATHODE
- STYLE 10:  
PIN 1. DRAIN  
2. SOURCE  
3. GATE
- STYLE 11:  
PIN 1. ANODE  
2. CATHODE  
3. CATHODE-ANODE
- STYLE 12:  
PIN 1. CATHODE  
2. CATHODE  
3. ANODE
- STYLE 13:  
PIN 1. SOURCE  
2. DRAIN  
3. GATE
- STYLE 14:  
PIN 1. CATHODE  
2. GATE  
3. ANODE
- STYLE 15:  
PIN 1. GATE  
2. CATHODE  
3. ANODE
- STYLE 16:  
PIN 1. ANODE  
2. CATHODE  
3. CATHODE
- STYLE 17:  
PIN 1. NO CONNECTION  
2. ANODE  
3. CATHODE
- STYLE 18:  
PIN 1. NO CONNECTION  
2. CATHODE  
3. ANODE
- STYLE 19:  
PIN 1. CATHODE  
2. ANODE  
3. CATHODE-ANODE
- STYLE 20:  
PIN 1. CATHODE  
2. ANODE  
3. GATE
- STYLE 21:  
PIN 1. GATE  
2. SOURCE  
3. DRAIN
- STYLE 22:  
PIN 1. RETURN  
2. OUTPUT  
3. INPUT
- STYLE 23:  
PIN 1. ANODE  
2. ANODE  
3. CATHODE
- STYLE 24:  
PIN 1. GATE  
2. DRAIN  
3. SOURCE
- STYLE 25:  
PIN 1. ANODE  
2. CATHODE  
3. GATE
- STYLE 26:  
PIN 1. CATHODE  
2. ANODE  
3. NO CONNECTION
- STYLE 27:  
PIN 1. CATHODE  
2. CATHODE  
3. CATHODE
- STYLE 28:  
PIN 1. ANODE  
2. ANODE  
3. ANODE

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